

ETRX.

Time: 3 Hours

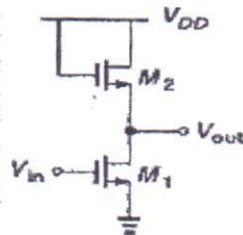
Max Marks: 80

- N.B. 1) Question No.1 is compulsory
2) Solve any three questions from the remaining questions.
3) Assume suitable data if necessary.

1 Solve any four of the following.

- (a) Explain trade-offs in analog design with the help of analog design octagon 5
- (b) For a n-channel MOSFET draw- a) a basic small signal model b) small signal model considering channel length modulation effect c) small signal model considering body effect 5
- (c) Explain the concept of clock feed through in the MOSFET sampling circuit 5
- (d) Compare performance of various op-amp topologies 5
- (e) Derive expression for input referred noise of CS stage 5

2 (a)



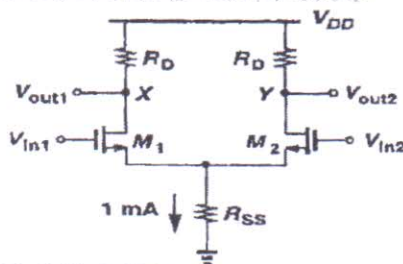
10

Identify the above network. Derive the gain equation of the above circuit.

- (b) Derive equation of differential gain, common mode gain and CMRR of a differential amplifier circuit. 10

3 (a)

The following circuit uses a resistor rather than a current source to define a tail 10



current of 1mA.

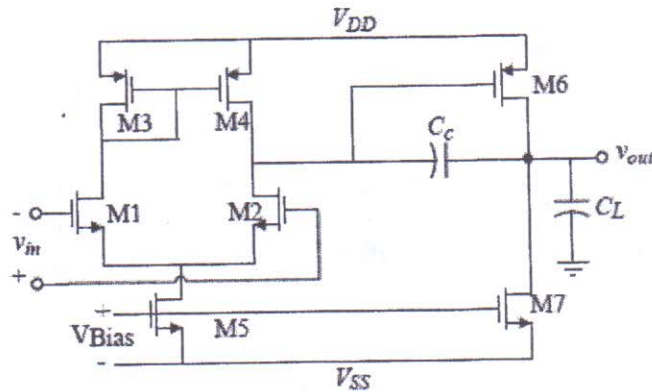
Assume $(W/L)_{1,2} = 25/0.5$, $\mu_n C_{ox} = 50 \mu A/V^2$, $V_{TH} = 0.6V$, $\lambda = 0$, $V_{DD} = 3V$

- (a) What is the required input CM for which R_{ss} sustains 0.5V? 10
- (b) Calculate R_D for a differential gain of 5
- (c) What happens at the output if input CM level is 50mV higher than the value calculated in (a)?
- (b) Derive expression for voltage gain A_v and output resistance R_o of source follower stage.

Q.4

Design two stage operational amplifiers that meet the following specifications

20



$$A_v > 3000V/V \quad V_{DD} = 2.5V \quad V_{SS} = -2.5V$$

Gain Bandwidth = 5MHz, Slew Rate $> 10V/\mu s$, 60° phase margin,

$$0.5V < V_{out} \text{ range} < 2V,$$

$$ICMR = -1.25V \text{ to } 2V,$$

$$P_{diss} \leq 2 \text{ mW}, C_L = 10pF$$

$$\text{Use } K_N = 100\mu A/V^2, K_P = 20\mu A/V^2, V_{TN} = |V_{TP}| = 0.5V, \lambda_N = 0.06V^{-1},$$

$$\lambda_P = 0.08V^{-1}, C_{ox} = 2.47fF/\mu m^2.$$

Verify that the designed circuit meets required voltage gain and power dissipation specifications

- 5 (a) Explain the charge injection mechanism in MOS sampling circuits and also describe the errors contributed by the above effect. 10
- (b) What is a band gap reference? Describe methods of implementation of band gap references. 10
- 6 Write short note on any four. 5
- (a) Necessity of Millers theorem. 5
- (b) Gilbert Cell. 5
- (c) Charge Pump PLL. 5
- (d) Comparison of full custom design and semi custom design. 5
- (e) Performance parameters of VCO. 5

(3 Hrs)

Total Marks: 80

- N.B. 1. Question No 1 is compulsory.
2. Solve any three from remaining.

- Q1 Answer any four : 20
- What is the need for Wireless Sensor network? Explain the WSN Protocol stack.
 - Explain the need for DWDM. Compare it with WDM.
 - "AAL 5 is a widely used ATM adaptation layer protocol": justify with
 - Mention the main functions of AAL
 - Name practical Examples that use services of AAL5.
 - Draw and explain different states of Bluetooth enabled device.
 - What are the different network security threats and safeguards? Explain.
- Q2 (a) Draw and explain Bluetooth protocol stack in detail. 10
- (b) Compare Ubiquitous and hierarchical access in Access Network design. Explain the steps for completing access layer design in detail. 10
- Q3 (a) In frame relay frame format, which bit is used to avoid network congestion? Draw and explain frame format of Frame relay. 10
- (b) Bring out the advantages of Optical networking. With a neat sketch, explain the SONET hardware components along with its functional layers. 10
- Q4 (a) What is a firewall? What are the capabilities and limitations of firewall? Discuss the different types of firewalls, along with their advantages and disadvantages. 10
- (b) With reference to ATM : 10
- Explain ATM Protocol architecture, bringing out the functions of ATM layer.
 - Compare the following ATM Adaptation Layer Protocols : AAL1, AAL2, AAL3/4, AAL5.
- Q5 (a) Draw and explain (i) IEEE 802.15.3 LR-WPAN Device architecture. 10
- (ii) ZigBee technology
- (b) Write short notes on : (i) B-ISDN model of ATM (ii) UWB 10
- Q6 Write a short note on ... (Any four) 20
- DMZ.
 - SNMP
 - RFID.
 - RMON.
 - VOFR

(3 Hours)

(Total Marks: 80)

Please check whether you have the right question paper.

- N.B.: 1) Question No.1 is compulsory.
2) Answer any Three out of remaining five questions
3) Draw the neat diagrams wherever necessary.

- Q1. 20M
A] Explain Air Bag deployment System in brief.
B] What are micro-actuators pertaining to MEMS Technology? Give two examples.
C] Define piezoresistivity and list out all piezo-resistive coefficients.
D] Explain the role of sacrificial layer in fabrication of MEMS devices.
- Q2. 10M
A] What are polymers? Draw structure of PMMA polymer and discuss its role in MEMS fabrication.
B] What do you understand by a clean room? Explain the steps in a standard RCA cycle during wafer cleaning. 10M
- Q3. 10M
A] State different types of pressure sensors and explain in detail, fabrication steps for a piezo-resistive pressure sensor.
B] Draw neat diagram and explain lift-off process. Why would one use it, in MEMS fabrication? 10M
- Q4. 10M
A] Explain the steps involved in fabrication of MEMS with proper illustration of surface micromachining.
B] Describe the DRIE process. How can DRIE achieve virtually perfect vertical etching? 10M
- Q5. 10M
A] What do you mean by wafer bonding? Explain with neat diagram, different wafer bonding techniques.
B] Describe the representative process flow for fabricating the ink jet printer head by Hewlett- Packard. Also explain the operating principle of this MEMS device with proper illustration of Ink-firing mechanism. 10M
- Q6. 20M
Write short note on:
A] MEMS packaging & its challenges.
B] High Aspect Ratio MEMS fabrication.
C] Role of MEMS in IoT.
D] MEMS Accelerometer.

(Time: 3 Hours)

[Total Marks:80]

NB.

- (1) Question No.1 is compulsory.
- (2) Attempt any three questions from remaining.
- (3) All questions carry equal marks.
- (4) Assume suitable data wherever necessary.

Q.1 Answer any four of the following:

- a) With neat sketch define Joint and Link parameters. (5)
- b) Explain how tool orientation is specified. (5)
- c) What is homogeneous transformation matrix? Give the transformation matrix for pure translation and pure rotation. (5)
- d) Explain template matching in robot vision. (5)
- e) Justify "Inverse kinematics problem is not unique." (5)

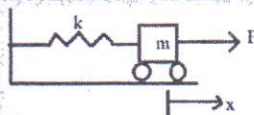
Q.2 a) Develop the DH representation of a four axis SCARA robot and obtain its arm matrix. (10)

- b) Let $F = \{f^1, f^2, f^3\}$ and $M = \{m^1, m^2, m^3\}$ be two initially coincident fixed and mobile orthonormal coordinate frames. Suppose the point P at the tool tip has mobile coordinates $[P]^M = [7, 3, 1]^T$. Find $[P]^F$ after the following transformations,
 1. Rotate M by $\pi/2$ radians about f^3 axis
 2. Then translate the rotated M by 4 units along f^1 axis.

Q.3 a) Find the new location and orientation of frame B after a differential rotation of 0.1 radians about the y axis followed by a differential translation of $[0.1, 0, 0.2]$. (10)

$$B = \begin{bmatrix} 0 & 0 & 1 & 10 \\ 1 & 0 & 0 & 5 \\ 0 & 1 & 0 & 3 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

- b) Derive the force acceleration relationship for a 1 DOF system given below using Lagrangian mechanics as well as Newtonian mechanics. Assume the motion is linear with no inertia. (10)



- Q.4 a) Explain robot motion planning using Bug 1 and Bug 2 algorithm. (10)
- b) What is a GVD? Sketch all the GVD's resulting due to the basic interactions of the obstacle. Derive the necessary equations. (10)

- Q.5 a) Explain Visibility Graph algorithm. (10)
- b) Explain the different moments to characterize shapes. (10)

Q.6 Write short notes on any four of the following: (20)

- a) Cartesian Space trajectory
- b) Potential Functions
- c) Shrink and Swell Operators
- d) Work Space Envelope
- e) Perspective Transformations

[Time: 3 Hours]

[Marks: 80]

Please check whether you have got the right question paper.

- N.B: 1. Question.No.1 is compulsory.
2. Attempt any three questions from the remaining five questions.

- Q.1 Answer the following: 20
- What is meant by frequency reuse? What is its effect on the co-channel interference?
 - State the radio specifications of GSM.
 - Compare GSM and CDMA technologies.
 - Explain the terms of soft, softer and soft-softer handoffs.
- Q.2 a) Draw a well labelled diagram and explain in detail the architecture of GSM. 10
- b) Explain GSM frame and time slot structure with the required figures. 10
- Q.3 a) Explain mobility and radio resource management in CDMA. 10
- b) With a neat block diagram, explain the working of a reverse channel CDMA IS95 modulation process for a single user? 10
- Q.4 a) What is WCDMA air interface and discuss the important parameters in it. 10
- b) Discuss the evolution path towards LTE and mention the important features of LTE. 10
- Q.5 a) Describe UMTS architecture with a neat diagram and interfaces. 10
- b) Compare 3G and 4G technologies. 05
- c) Write a detailed note on mobile IP. 05
- Q.6 Write short notes on: 20
- WiMax
 - GPRS technology
 - RFID
 - MANET